

# BT1B-6781 0.5MHz-30MHz 1kW

 Scientific and Industrial Applications



The BTB series is a range of class A RF power amplifiers covering the 0.5MHz to 30MHz frequency range

- Rugged, solid-state design high reliability
- Extremely high phase and amplitude stability
- Very fast pulse rise/fall times
- High linearity
- Very low interpulse noise
- Competitively priced

# RF Specifications

RF Specifications				
Rated Power	1kW minimum PEP for input power of 0dBm			
P1dB	800W minimum Minimum output power at P1dB compression			
Gain	60dB minimum			
Туре	Class A MOSFET			
Frequency	0.5MHz-30MHz			
Gain flatness	±1.5dB maximum (measured at 1/10th rated output power)			
Max. duty cycle	5% Maximum GATE duty cycle			
Max. pulse width	500μs Maximum GATE pulse width			
Pulse droop	1dB maximum Measured at max. pulse width at P1dB level			
Pulse rise and fall times	Risetime: 200ns typical Falltime: 100ns typical using a pre-gated RF input signal			
GATE rise and fall times	Risetime: 300ns typical Falltime: 150ns typical			
Gate delay	Rising edge: 1µs typical Falling edge: 500ns typical Rising edge measured from rising edge of GATE pulse to 90% RF output voltage. Falling edge measured from falling edge of GATE pulse to 10% RF output voltage			
Harmonics	<-30dBc			
Spurious	<-60dBc maximum			
Output noise (blanked)	<10dB above thermal (100kHz bandwidth)			
Phase change/power	<10° from -40dB to full power			
Phase stability	<1° across 500μs pulse			
Output sample	-60dB into 50 $\Omega$ (forward voltage sample)			
Input/output impedance	50 Ω nominal			
Load VSWR	Tolerates at least 3:1 @ full rated power without shut down			
Gain control range	10dB minimum for 0-5V control voltage			
RF Input	0dBm nominal, 10dBm for no damage			
GATE (blanking)	Logic low = Blank, logic high = unblank. CMOS and TTL compatible			

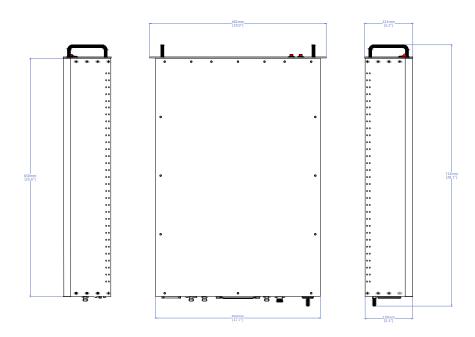
### **Electrical Specifications**

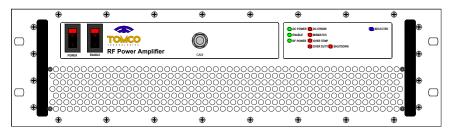
Mains supply voltage	110-240V, 50-60Hz, single phase	
Rated Power	1kVA maximum	
Mains inlet	1 x IEC inlet (mains power cord supplied)	

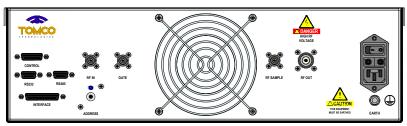


# **Mechanical Specifications**

Connectors	RF IN: BNC female GATE: BNC female RF SAMPLE: BNC female RF OUT: N type female INTERFACE: DB25 female  Other connectors types available on request		
Dimensions	Chassis size: 450mmW (17.7"W) x 650mmD (19.7"D) x 129mmH (5.1"H) Total size: 482mmW (19"W) x 713mm (22.2"D) x 131mm (5.2"H) Rack compatibility: 19" 3RU		
Weight	approx. 20kg (44lbs)		
Enclosure classification	IP20		







# **RF Amplifier Data Sheet**

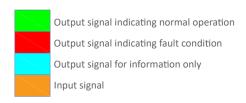


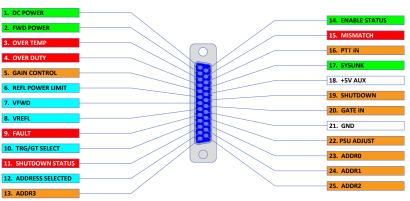
### Protection

Load VSWR	Tolerates up to VSWR 3:1 at full rated power without shutdown Self-resetting shutdown protection activates if VSWR limits are exceeded	
Over temperature	Self-resetting shutdown protection activates if thermal limits are exceeded	
Duty cycle	Duty cycle limit is determined from the GATE signal duty cycle. Self-resetting shutdown protection activates if duty cycle limit is exceeded	
Pulse width	Pulse width limit is determined from the GATE signal pulse width. Self-resetting shutdown protection activates if pulse width limit is exceeded	

### **Monitoring and Control**

Front panel switches	Power (turns on DC power) Enable (enables RF) Gain Control Knob (gain adjustment via front panel)			
Front panel LEDs	DC POWER     DC ERROR     SELECTED     ENABLE     MISMATCH     SHUTDOWN     RF POWER     OVER TEMP     OVER DUTY			
Parallel interface	25-pin D-connector (pinout available at <u>www.tomcorf.com/pdf/interface.pdf</u> )*			





# **Environmental**

\*Some functions may be unavailable on select amplifier models

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General	Intended for use only in controlled, indoor environment. Non-consumer product for industrial and scientific use. This product is not authorised for stand-alone on-air use. Additional systems, hardware and considerations are required to meet local spectral management regulations. Compliance of the final complete system is the responsibility of the end user.		
Cooling	Forced air, front to rear		
Operating temperature	+5°C to +40°C		
Storage temperature	-20°C to +60°C		
Humidity	80% for temperature up to 31°C, decreasing linearly to 50% relative humidity at 40°C		
Operating altitude	Up to 2000m		
Pollution degree	2		
Transient voltage compatibilty	Category II, in line with IEC 60364-4-44:2007		
Electromagnetic compatibility	In line with IEC61326-1:2012 ISM equipment, Group 1, Class A For use only in shielded areas. ENC55011 (CISPR 11) limits exceeded by up to 60dB		
Safety	In line with IEC61010-1:2010		

# Change record

Document/Issue number	Originator	Date	Change
DS006781A	TD	22/09/19	Original